

FDMS86500DC

Data Sheet

Trans MOSFET N-CH Si 60V 29A 8-Pin Power 56 T/R

Manufacturers ON Semiconductor, LLC

Package/Case Power 56

Product Type Transistors

RoHS Green

Lifecycle



Images are for reference only

ONSEMI

Please submit RFQ for FDMS86500DC or Email to us: sales@ovaga.com We will contact you in 12 hours.



General Description

This N-Channel MOSFET is produced using an advanced Power Trench® process. Advancements in both silicon and Dual Cool™ package technologies have been combined to offer the lowest rDS(on) while maintaining excellent switching performance by extremelylow Junction-to-Ambient thermal resistance.

Features Application

Dual CoolTM Top Side Cooling PQFN package

Max = 10 V,>

Max = 8 V,>

High performance technology for extremely low rDS(on)

100% UIL Tested

RoHS Compliant



Related Products



FDC645N

ON Semiconductor, LLC SSOT-6



FDC6305N

ON Semiconductor, LLC SSOT-6



FDD8647L

ON Semiconductor, LLC TO-252-3



FDD5N50NZTM

ON Semiconductor, LLC TO-252



FDC637BNZ

ON Semiconductor, LLC SSOT-6



FDC602P

ON Semiconductor, LLC SOT163



FDB070AN06A0

ON Semiconductor, LLC TO-263



FDD3670

ON Semiconductor, LLC TO-252AA